

# **N-Channel Power MOSFET**

40V, 54A, 11mΩ

#### **FEATURES**

- Low R<sub>DS(ON)</sub> to minimize conductive losses
- Logic level
- Low gate charge for fast power switching
- 100% UIS and R<sub>g</sub> tested.
- 175°C Operating Junction Temperature
- Compliant to RoHS directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

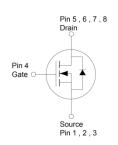
	$\Delta TI$	<b>ONS</b>

- BLDC Motor Control
- Battery Power Management
- DC-DC converter
- Secondary Synchronous Rectification

KEY PERFORMANCE PARAMETERS				
PARAMETER		VALUE	UNIT	
$V_{DS}$		40	V	
R <sub>DS(on)</sub> (max)	$V_{GS} = 10V$	11		
	$V_{GS} = 4.5V$	16	mΩ	
$Q_g$		12	nC	







Note: MSL 1 (Moisture Sensitivity Level) per J-STD-020

ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25°C unless otherwise noted)					
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-Source Voltage		$V_{DS}$	40	V	
Gate-Source Voltage		$V_{GS}$	±20	V	
Continuous Drain Current (Note 1)	$T_C = 25^{\circ}C$		54	^	
Continuous Drain Current	$T_{C} = 25^{\circ}C$ $T_{A} = 25^{\circ}C$	I <sub>D</sub>	12	A	
Pulsed Drain Current		I <sub>DM</sub>	216	А	
Single Pulse Avalanche Current (Note 2)		I <sub>AS</sub>	16	А	
Single Pulse Avalanche Energy (Note 2)		E <sub>AS</sub>	38	mJ	
Total Davier Dissipation	$T_C = 25^{\circ}C$	Б	68	W	
Total Power Dissipation	T <sub>C</sub> = 125°C	P <sub>D</sub>	23		
Total Dawer Dissipation	$T_A = 25$ °C	Б	3.1	\\\\	
Total Power Dissipation	T <sub>A</sub> = 125°C	P <sub>D</sub>	1	W	
Operating Junction and Storage Temp	erature Range	T <sub>J</sub> , T <sub>STG</sub>	- 55 to +175	°C	

THERMAL PERFORMANCE				
PARAMETER	SYMBOL	LIMIT	UNIT	
Junction to Case Thermal Resistance	R <sub>eJC</sub>	2.2	°C/W	
Junction to Ambient Thermal Resistance	$R_{\Theta JA}$	48	°C/W	

**Thermal Performance Note:**  $R_{\Theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistances. The case-thermal reference is defined at the solder mounting surface of the drain pins.  $R_{\Theta JA}$  is guaranteed by design while  $R_{\Theta CA}$  is determined by the user's board design. The  $R_{\Theta JA}$  limit presented here is based on mounting on a 1 in<sup>2</sup> pad of 2 oz copper.

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ELECTRICAL SPECIFICATIONS (T <sub>A</sub> = 25°C unless otherwise noted)						
PARAMETER	CONDITIONS	SYMBOL	MIN	TYP	MAX	UNIT
Static						
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$	BV <sub>DSS</sub>	40			V
Gate Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \mu A$	$V_{GS(TH)}$	1	1.9	2.5	V
Gate-Source Leakage Current	$V_{GS} = \pm 20V, V_{DS} = 0V$	I <sub>GSS</sub>			±100	nA
	$V_{GS} = 0V, V_{DS} = 40V$				1	μA
Drain-Source Leakage Current	$V_{GS} = 0V, V_{DS} = 40V$ $T_{J} = 125^{\circ}C$	I <sub>DSS</sub>			100	
Drain-Source On-State Resistance	$V_{GS} = 10V, I_D = 12A$	Ь		8	11	mΩ
(Note 3)	$V_{GS} = 4.5V, I_{D} = 10A$	R <sub>DS(on)</sub>		12	16	
Forward Transconductance (Note 3)	$V_{DS} = 10V, I_{D} = 12A$	g <sub>fs</sub>		34		S
Dynamic (Note 4)						
Total Gate Charge	$V_{GS} = 10V, V_{DS} = 20V,$ $I_{D} = 12A$	$Q_g$		23		
Total Gate Charge	$V_{GS} = 4.5V, V_{DS} = 20V,$	$Q_g$		12		nC
Gate-Source Charge		Q <sub>gs</sub>		4		
Gate-Drain Charge	I <sub>D</sub> = 10A	$Q_{gd}$		6		
Input Capacitance		C <sub>iss</sub>		1269		
Output Capacitance	$V_{GS} = 0V, V_{DS} = 20V$	C <sub>oss</sub>		142		pF
Reverse Transfer Capacitance	f = 1.0MHz	C <sub>rss</sub>		82		
Gate Resistance	f = 1.0MHz	$R_g$	0.5	1.7	3.4	Ω
Switching (Note 4)						
Turn-On Delay Time		t <sub>d(on)</sub>		1		
Turn-On Rise Time	$V_{GS} = 10V, V_{DS} = 20V,$ $I_D = 12A, R_G = 2\Omega$	t <sub>r</sub>		20		
Turn-Off Delay Time		t <sub>d(off)</sub>		13		ns
Turn-Off Fall Time		t <sub>f</sub>		13		
Source-Drain Diode						
Forward Voltage (Note 3)	V <sub>GS</sub> = 0V, I <sub>S</sub> = 12A	$V_{SD}$			1.2	V
Reverse Recovery Time	I <sub>S</sub> = 12A ,	t <sub>rr</sub>		15		ns
Reverse Recovery Charge	dl/dt = 100A/µs	Q <sub>rr</sub>		7		nC

#### Notes:

- 1. Silicon limited current only.
- 2. L=0.3mH,  $V_{GS}=10V$ ,  $V_{DD}=25V$ ,  $R_{G}=25\Omega$ ,  $I_{AS}=16A$ , Starting  $T_{J}=25^{\circ}C$
- 3. Pulse test: Pulse Width  $\leq$  300µs, duty cycle  $\leq$  2%.
- 4. Switching time is essentially independent of operating temperature.

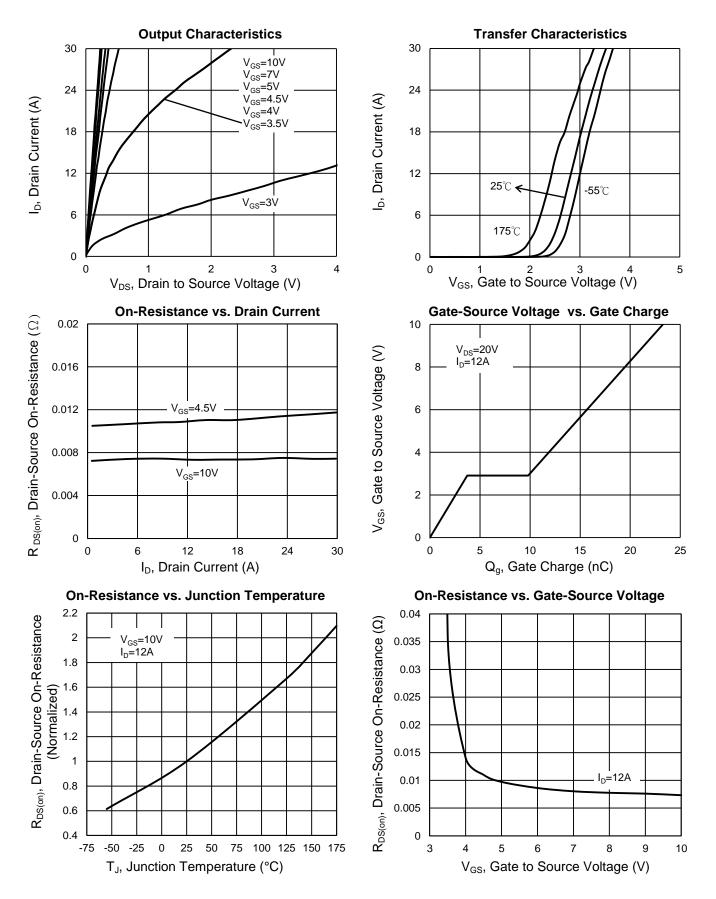
## **ORDERING INFORMATION**

PART NO.	PACKAGE	PACKING
TSM110NB04LCR RLG	PDFN56	2,500pcs / 13" Reel



#### **CHARACTERISTICS CURVES**

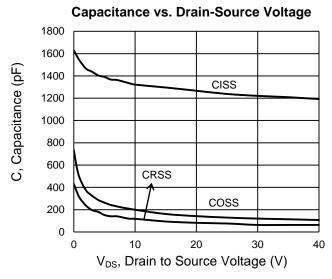
 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 

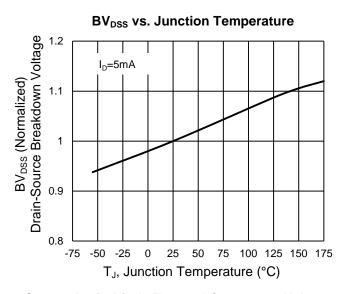


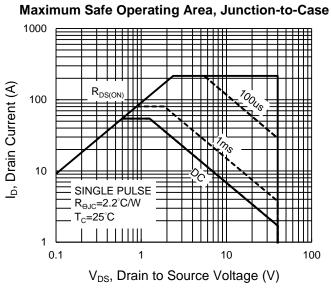


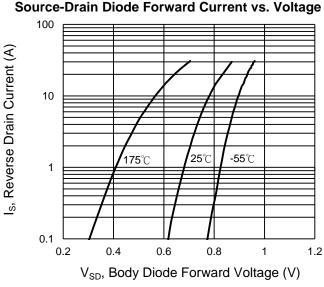
#### **CHARACTERISTICS CURVES**

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 

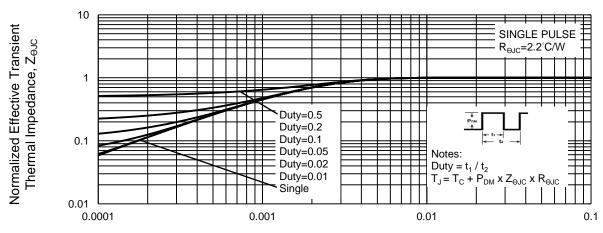








#### Normalized Thermal Transient Impedance, Junction-to-Case

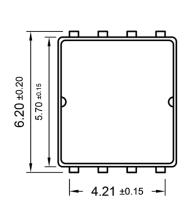


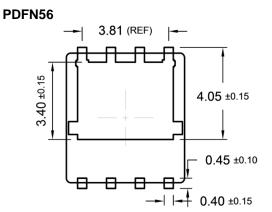
t, Square Wave Pulse Duration (sec)

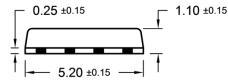


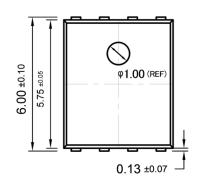


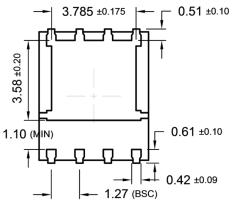
## PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)





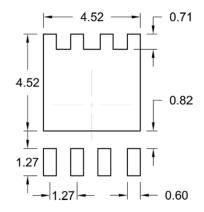




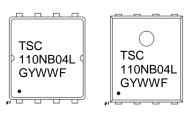




# SUGGESTED PAD LAYOUT (Unit: Millimeters)



## **MARKING DIAGRAM**



G = Halogen Free

Υ = Year Code

WW = Week Code (01~52)

= Factory Code

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